

# HAT2215R

## Silicon N Channel Power MOSFET High Speed Power Switching

REJ03G0486-0301

Rev.3.01

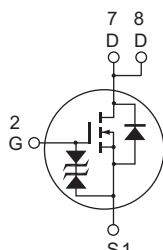
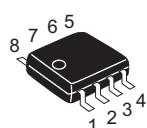
Jan 20, 2017

### Features

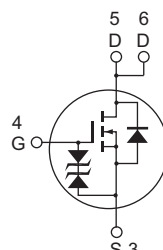
- Low on-resistance
- Capable of 4.5 V gate drive
- High density mounting

### Outline

RENESAS Package code: PRSP0008DD-D  
(Package name: SOP-8<FP-8DAV>)



MOS1



MOS2

1, 3 Source  
2, 4 Gate  
5, 6, 7, 8 Drain

### Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DS}$	80	V
Gate to source voltage	$V_{GS}$	$\pm 20$	V
Drain current	$I_D$	3.4	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	20.4	A
Reverse drain current	$I_{DR}$	3.4	A
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	1.5	W
Channel dissipation	$P_{ch}$ <sup>Note3</sup>	2.2	W
Channel temperature	$T_{ch}$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Notes: 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$

2. 1 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm),  $PW \leq 10 s$

3. 2 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm),  $PW \leq 10 s$

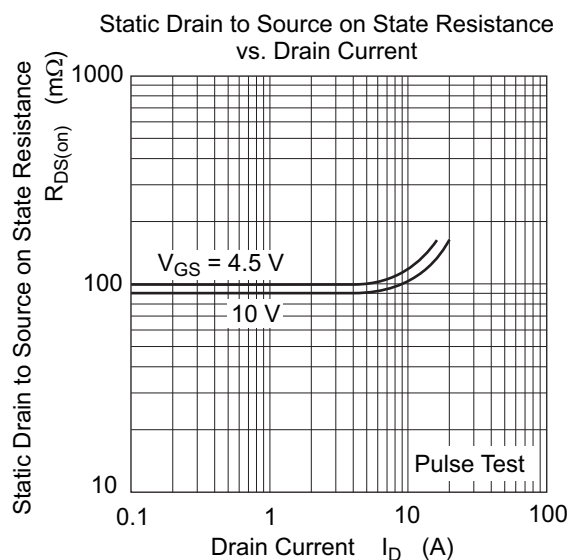
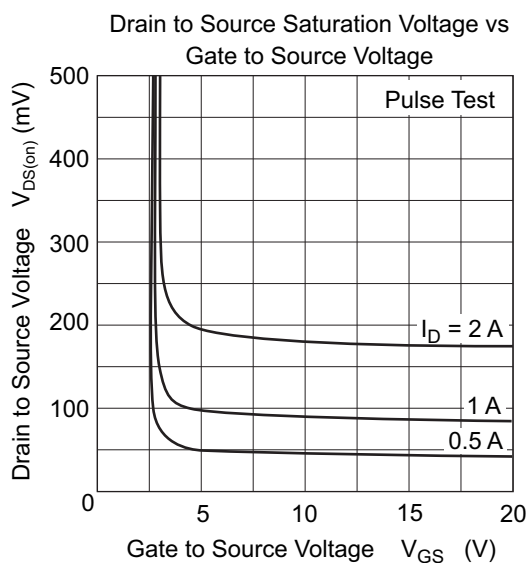
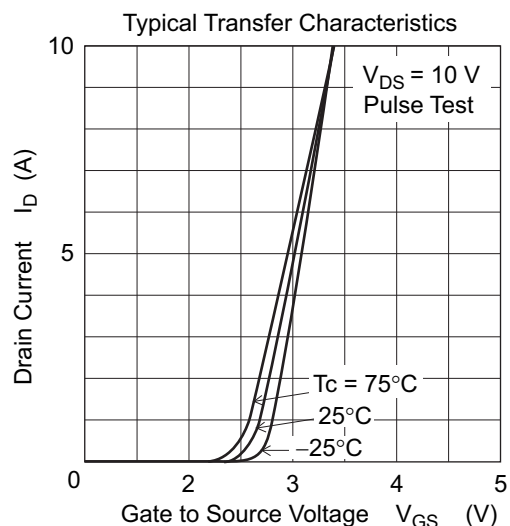
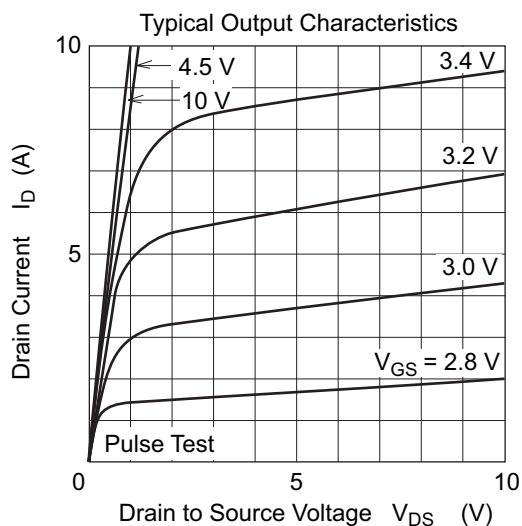
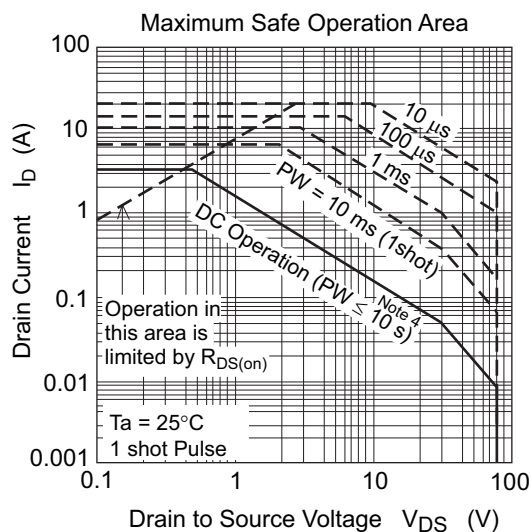
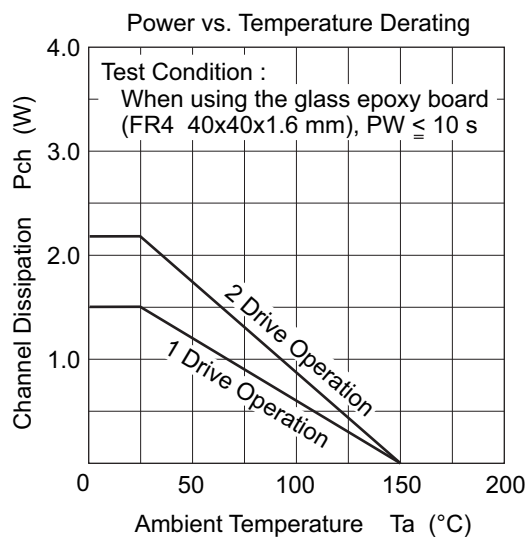
## Electrical Characteristics

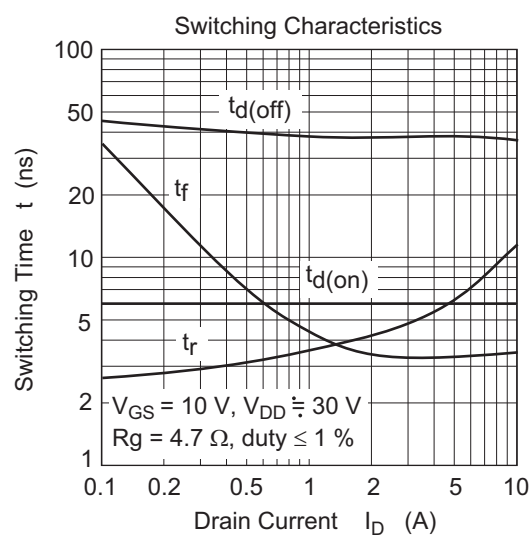
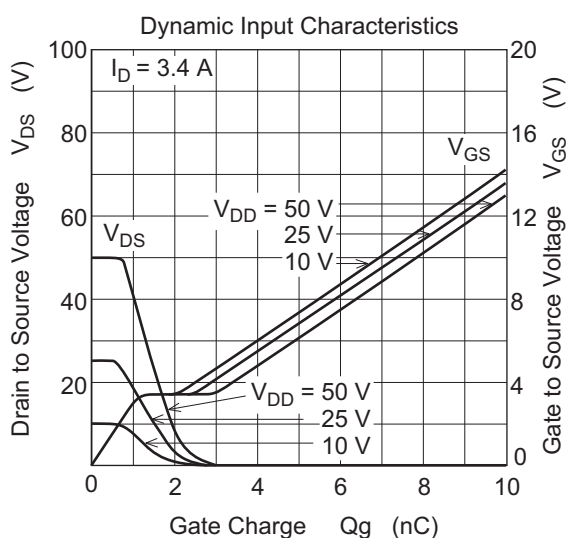
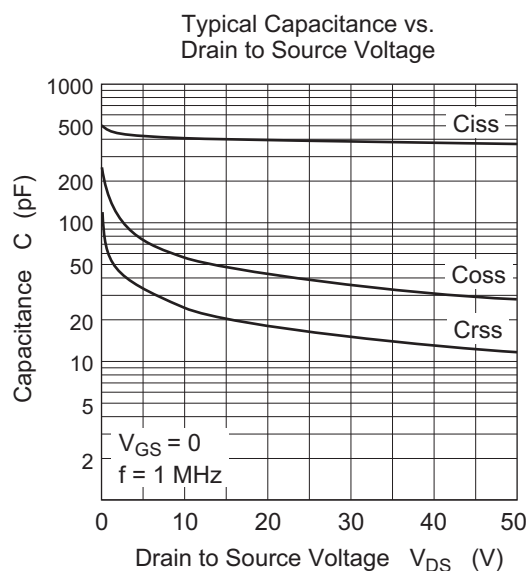
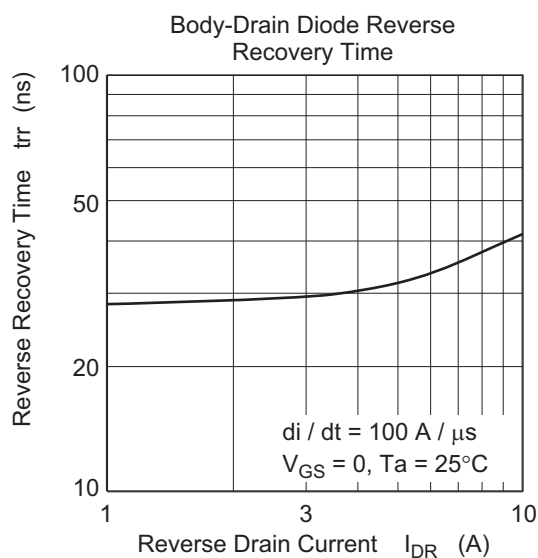
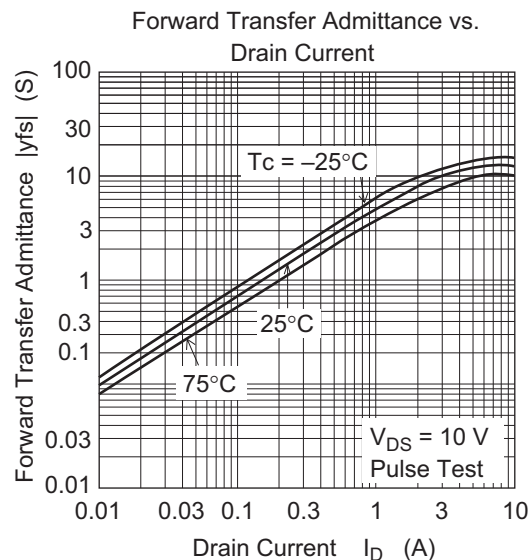
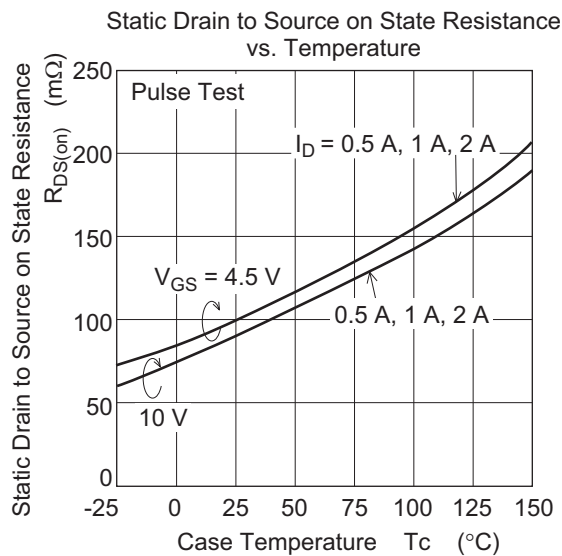
(Ta = 25°C)

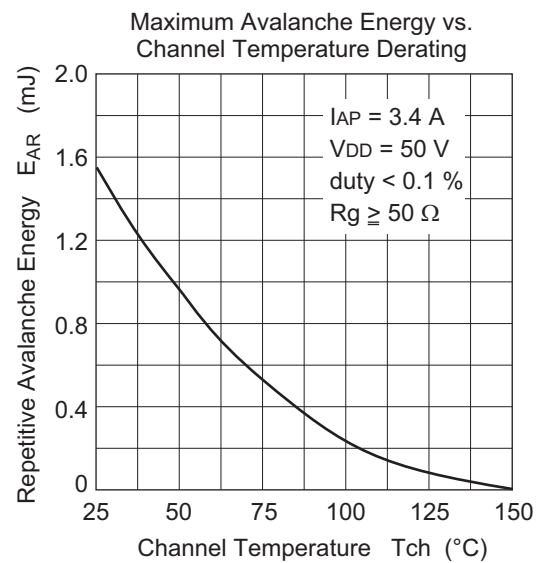
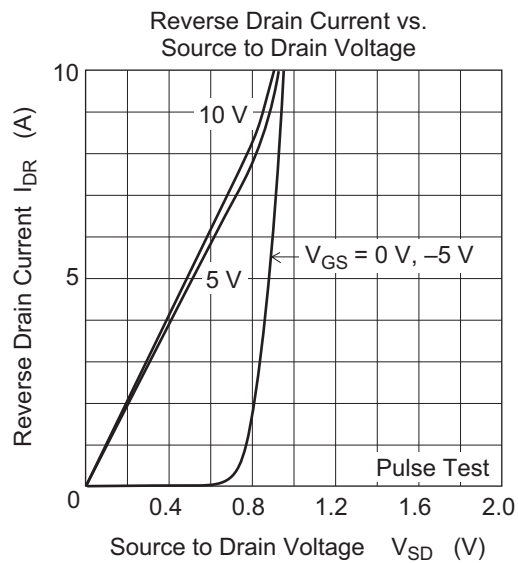
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	80	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	$\pm 20$	—	—	V	$I_D = \pm 100 \text{ }\mu\text{A}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 10$	$\mu\text{A}$	$V_{GS} = \pm 16 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 80 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	88	115	$\text{m}\Omega$	$I_D = 1.7 \text{ A}$ , $V_{GS} = 10 \text{ V}$ Note4
	$R_{DS(on)}$	—	100	145	$\text{m}\Omega$	$I_D = 1.7 \text{ A}$ , $V_{GS} = 4.5 \text{ V}$ Note4
Forward transfer admittance	$ y_{fs} $	4.2	7.0	—	S	$I_D = 1.7 \text{ A}$ , $V_{DS} = 10 \text{ V}$ Note4
Input capacitance	$C_{iss}$	—	400	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	$C_{oss}$	—	57	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	$C_{rss}$	—	24	—	pF	$f = 1 \text{ MHz}$
Total gate charge	$Q_g$	—	7.3	—	nC	$V_{DD} = 25 \text{ V}$
Gate to source charge	$Q_{gs}$	—	1.1	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	1.3	—	nC	$I_D = 3.4 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	6.0	—	ns	$V_{GS} = 10 \text{ V}$ , $I_D = 1.7 \text{ A}$
Rise time	$t_r$	—	4.0	—	ns	$V_{DD} \approx 30 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	39	—	ns	$R_L = 17.6 \text{ }\Omega$
Fall time	$t_f$	—	3.5	—	ns	$R_g = 4.7 \text{ }\Omega$
Body-drain diode forward voltage	$V_{DF}$	—	0.83	1.08	V	$I_F = 3.4 \text{ A}$ , $V_{GS} = 0$ Note4
Body-drain diode reverse recovery time	$t_{rr}$	—	30	—	ns	$I_F = 3.4 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

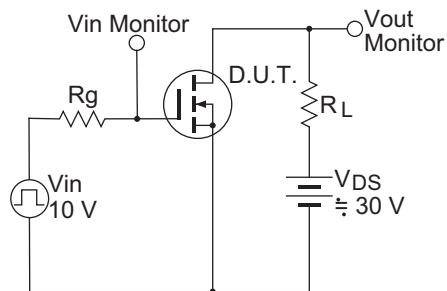
## Main Characteristics



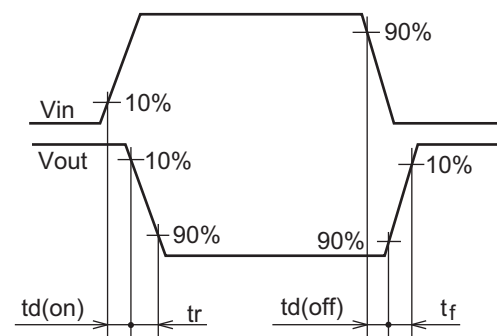




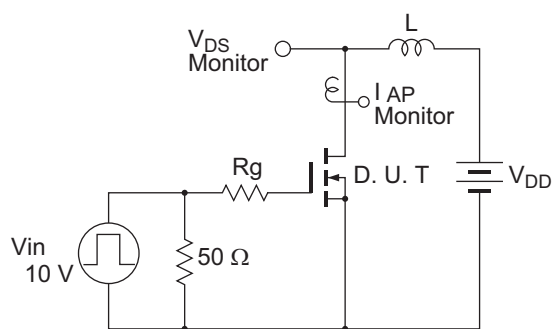
Switching Time Test Circuit



Switching Time Waveform

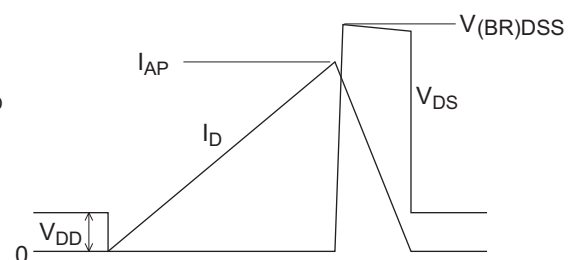


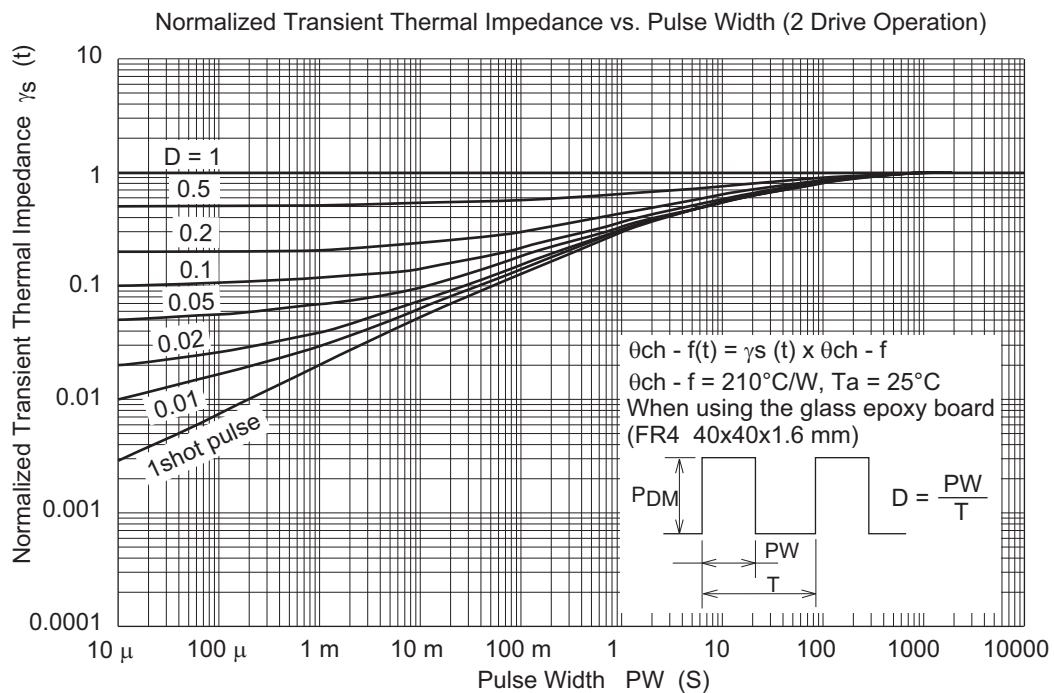
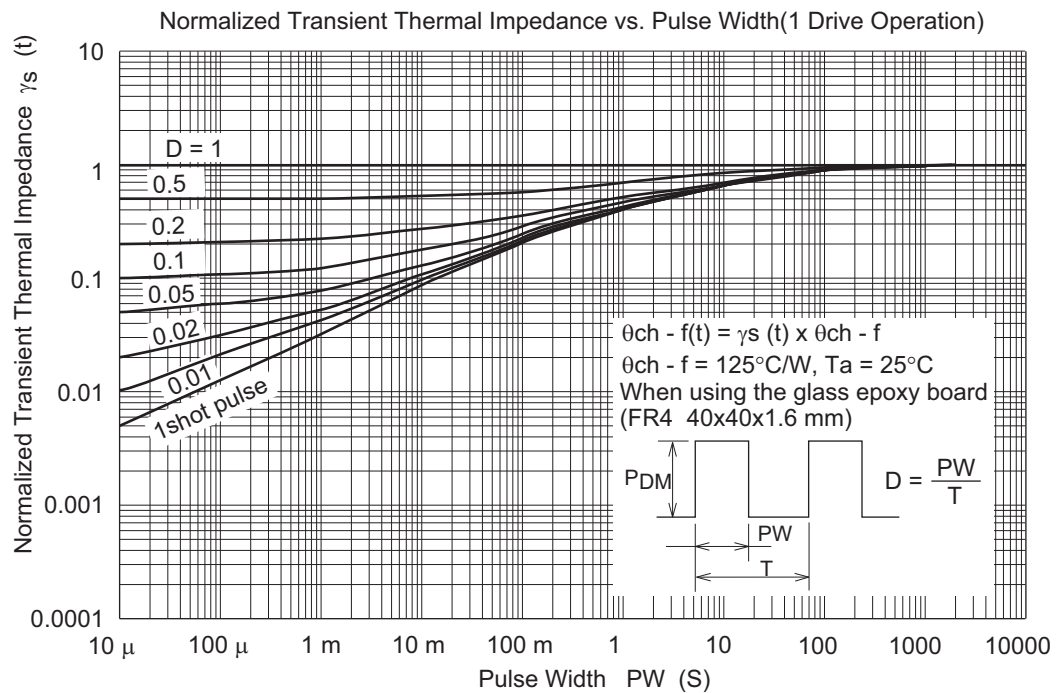
Avalanche Test Circuit



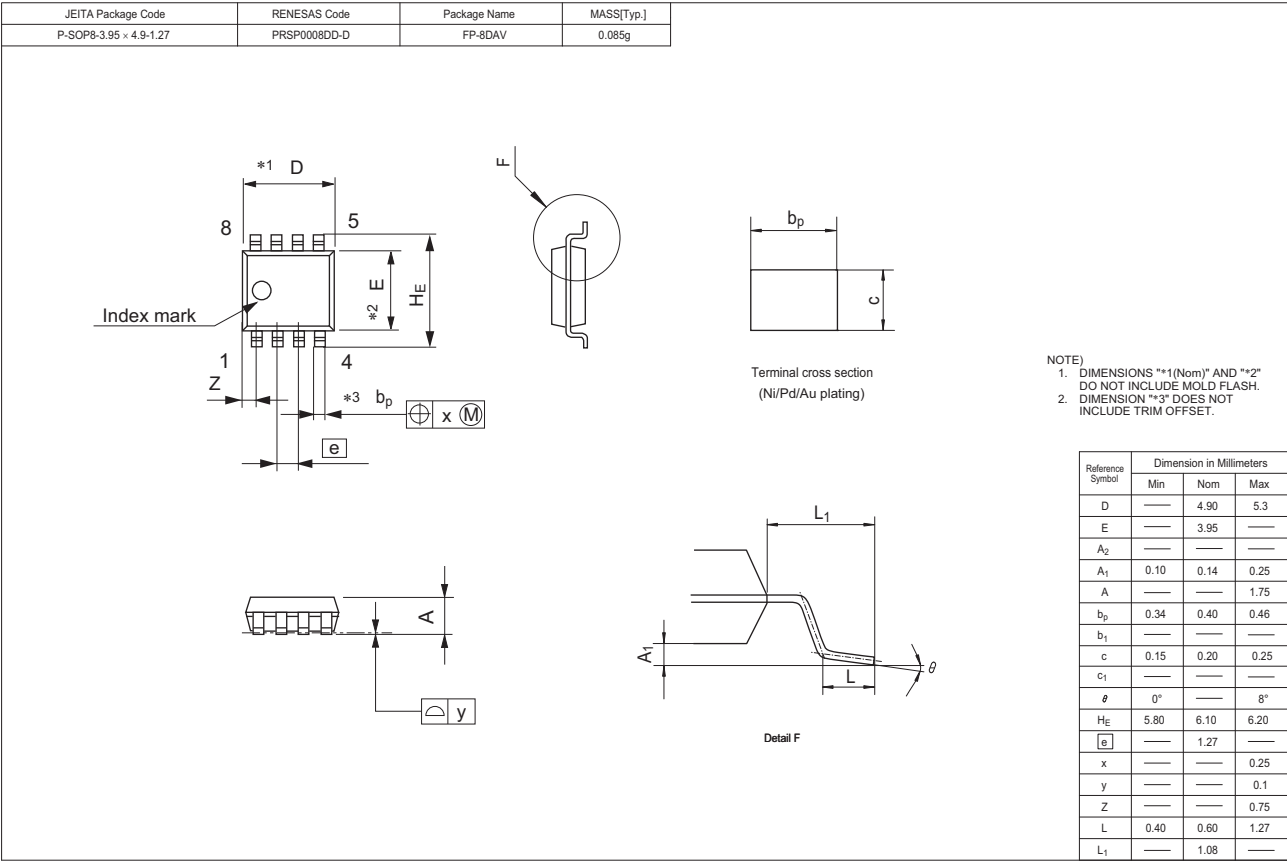
Avalanche Waveform

$$E_{AR} = \frac{1}{2} L \cdot I_{AP}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$$





Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HAT2215R-EL-E	2500 pcs	Taping

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